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# AXIAL LEADED HERMETICALLY SEALED FAST RECTIFIER DIODE

- Low reverse recovery time
- · Hermetically sealed in Metoxilite fused metal oxide
- Low switching losses
- Low forward voltage drop
- Soft, non-snap off, recovery characteristics

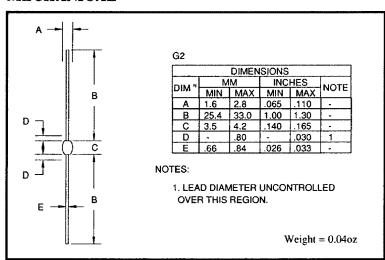
## QUICK REFERENCE DATA

- $V_R = 200 1000V$
- $I_F = 2.00A$
- $t_{rr} = 150 500$ nS
- $I_R = 0.5 \mu A$

## ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

	Symbol	1N5615 S2F	1N5617 S4F	1N5619 S6F	1N5621 S8F	1N5623 S0F	Unit
Working reverse voltage	V <sub>RWM</sub>	200	400	600	800	1000	V
Repetitive reverse voltage	V <sub>RRM</sub>	200	400	600	800	1000	V
Average forward current (@ 55°C, lead length 0.375")	I <sub>F</sub> (AV)			<b>-</b> 2.0 <b>-</b>	,		A
Repetitive surge current (@ 55°C in free air, lead length 0.375")	$I_{FRM}$	-		<b>-</b> 6.0 -			A
Non-repetitive surge current (tp = 8.3mS, @ VR & Tjmax)	I <sub>FSM</sub>	-		<b>-</b> 25 <b>-</b>			Α
Storage temperature range	Tstg			55 to +17	75 ——		°C
Operating temperature range	TOP	-		55 to +17	75 <del></del>		°C

#### **MECHANICAL**



These products are qualified to MIL-PRF-19500/429 and are preferred parts as listed in MIL-STD-701. They can be supplied fully released as JAN, JANTX, JANTXV and JANS version. These products are qualified in Europe to DEF STAN 59-61 (PART 80)/029.

## **ELECTRICAL CHARACTERISTICS** (@ 25°C unless otherwise specified)

·	Symbol	1N5615 1N S2F S	N5617 S4F	1N5619 S6F	1N5621 S8F	1N5623 S0F	Unit
Average forward current max. (pcb mounted; $T_A = 55^{\circ}C$ ) for sine wave for square wave (d = 0.5)	I <sub>F</sub> (AV) I <sub>F</sub> (AV)	4					A A
Average forward current max. $(T_L = 55^{\circ}C; L = 3/8")$ for sine wave for square wave $I^2t$ for fusing (t = 8.3mS) max.	I <sub>F(AV)</sub> I <sub>F(AV)</sub> I <sup>2</sup> t	<b>=</b>		2.00 -			A A A <sup>2</sup> S
Forward voltage drop max. @ $I_F = 1.0A$ , $T_j = 25^{\circ}C$	$V_{\mathbf{F}}$	4		<b>-</b> 1.2 <b>-</b>		<b>→</b>	v
Reverse current max. @ $V_{RWM}$ , $T_j = 25^{\circ}C$ @ $V_{RWM}$ , $T_j = 100^{\circ}C$	I <sub>R</sub> I <sub>R</sub>	<del></del>		- 0.5 - - 25 -		<b>→</b>	μΑ μΑ
Reverse recovery time max. 0.5A I <sub>F</sub> to 1.0A I <sub>R</sub> . Recovers to 0.25A I <sub>RR</sub> .	t <sub>rr</sub>	150	150	250	300	500	nS
Junction capacitance typ. @ $V_R = 5V$ , $f = 1MHz$	C <sub>j</sub>	27	27	27	18	18	ρF

### THERMAL CHARACTERISTICS

	Symbol	1N5615 S2F	5 1N5617 S4F	1N5619 S6F	1N5621 S8F	1N5623 S0F	Unit
Thermal resistance - junction to lead Lead length = 0.375" Lead length = 0.0"	R <sub>0</sub> jl R <sub>0</sub> jl	<b>-</b>		— 38 — — 7 —		<b></b>	°C/W °C/W
Thermal resistance - junction to amb. on 0.06" thick pcb. 1 oz. copper.	R <sub>0JA</sub>	<b>←</b>		<b>–</b> 95 <b>–</b>			°C/W

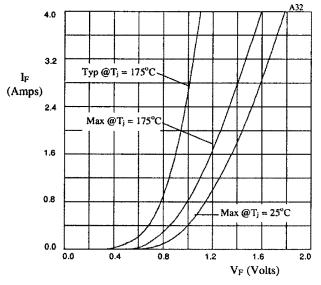


Fig 1. Forward voltage drop as a function of forward current.

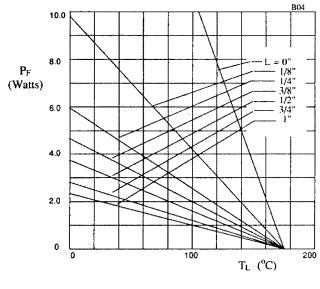


Fig 2. Maximum power versus lead temperature.

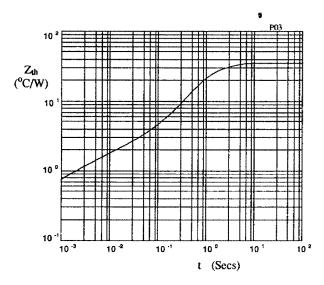


Fig 3. Transient thermal impedance characteristic.

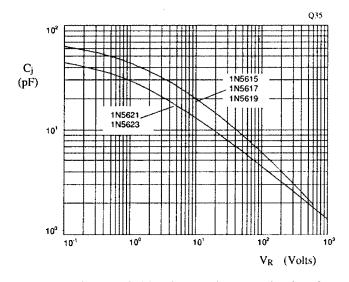


Fig 4. Typical junction capacitance as a function of reverse voltage.

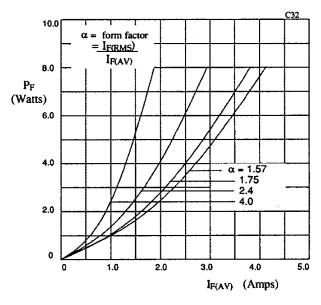


Fig 5. Forward power dissipation as a function of forward current, for sinusoidal operation.

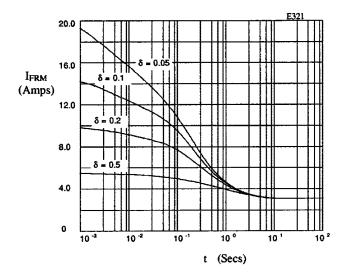


Fig 7. Typical repetitive forward current as a function of pulse width at  $55^{\circ}C$ ;  $R_{\theta JL} = 35\ ^{\circ}C/W$ ;  $V_{RWM}$  during  $1 - \delta$ .

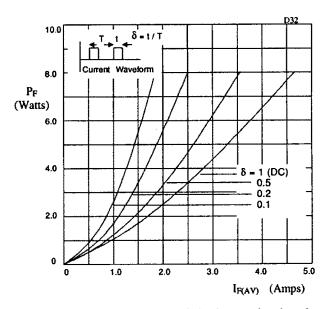


Fig 6. Forward power dissipation as a function of forward current, for square wave operation.

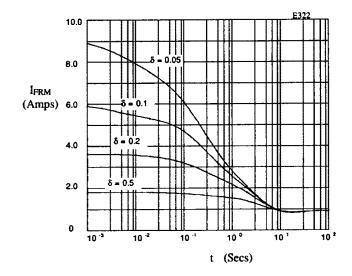


Fig 8. Typical repetitive forward current as a function of pulse width at  $100^{\circ}$ C;  $R_{\theta JL} = 95$  °C/W;  $V_{RWM}$  during  $1 - \delta$ .